2SC2545, 2SC2546, 2SC2547

Silicon NPN Epitaxial

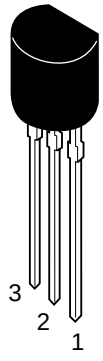
HITACHI

Application

- Low frequency low noise amplifier
- Complementary pair with 2SA1083, 2SA1084 and 2SA1085

Outline

TO-92 (1)



1. Emitter
2. Collector
3. Base

Hitachi semiconductor

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	2SC2545	2SC2546	2SC2547	Unit
Collector to base voltage	V_{CBO}	60	90	120	V
Collector to emitter voltage	V_{CEO}	60	90	120	V
Emitter to base voltage	V_{EBO}	5	5	5	V
Collector current	I_C	100	100	100	mA
Emitter current	I_E	–100	–100	–100	mA
Collector power dissipation	P_C	400	400	400	mW
Junction temperature	Tj	150	150	150	°C
Storage temperature	Tstg	–55 to +150	–55 to +150	–55 to +150	°C

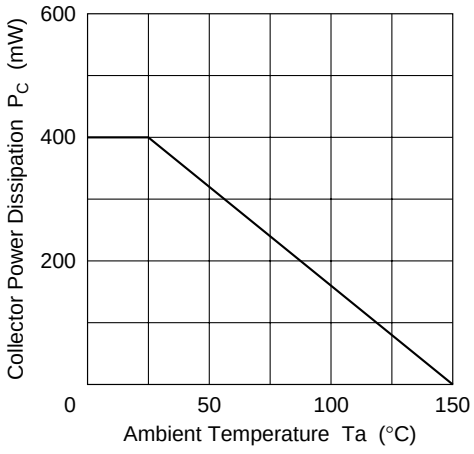
Electrical Characteristics (Ta = 25°C)

Item	Symbol	2SC2545			2SC2546			2SC2547			Unit	Test conditions
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max		
Collector to base breakdown voltage	$V_{(BR)CBO}$	60	—	—	90	—	—	120	—	—	V	I_C = 10 µA, I_E = 0
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	60	—	—	90	—	—	120	—	—	V	I_C = 1 mA, R_{BE} = ∞
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	—	—	5	—	—	5	—	—	V	I_E = 10 µA, I_C = 0
Collector cutoff current	I_{CBO}	—	—	0.1	—	—	0.1	—	—	0.1	µA	V_{CB} = 50 V, I_E = 0
Emitter cutoff current	I_{EBO}	—	—	0.1	—	—	0.1	—	—	0.1	µA	V_{EB} = 2 V, I_C = 0
DC current transfer ratio	h_{FE}*[1]	250	—	1200	250	—	1200	250	—	800		V_{CE} = 12 V, I_C = 2 mA
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	0.2	—	—	0.2	—	—	0.2	V	I_C = 10 mA, I_B = 1 mA
Base to emitter voltage	V_{BE}	—	0.6	—	—	0.6	—	—	0.6	—	V	V_{CE} = 12 V, I_C = 2 mA
Gain bandwidth product	f_T	—	90	—	—	90	—	—	90	—	MHz	V_{CE} = 12 V, I_C = 2 mA
Collector output capacitance	Cob	—	3.0	—	—	3.0	—	—	3.0	—	pF	V_{CB} = 10 V, I_E = 0, f = 1 MHz
Noise voltage referred input	e_n	—	0.5	—	—	0.5	—	—	0.5	—	nV/$\sqrt{Hz}$	V_{CE} = 6V, I_C = 10 mA, f = 1 kHz, R_g = 0, Δf = 1Hz

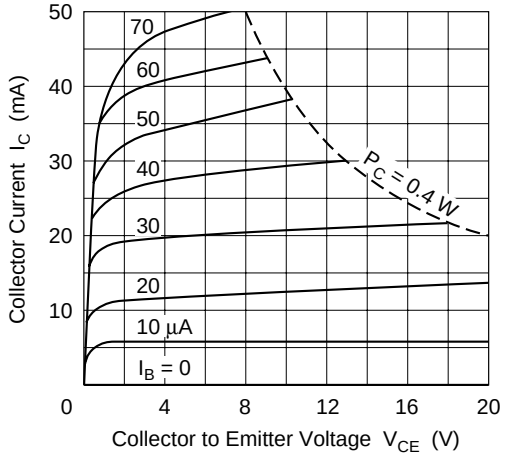
Note: 1. The 2SC2545, 2SC2546 and 2SC2547 are grouped by h_{FE} as follows.

	D	E	F
2SC2545, 2SC2546	250 to 500	400 to 800	600 to 1200
2SC2547	250 to 500	400 to 800	—

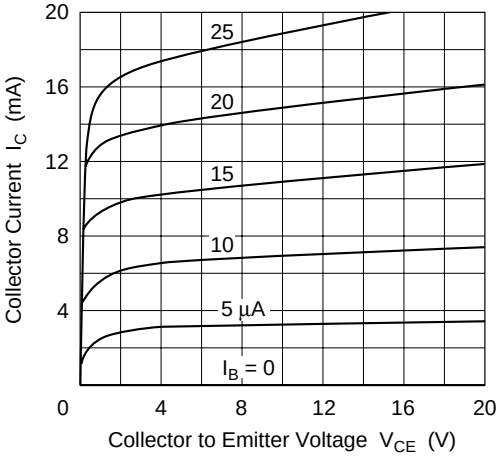
Maximum Collector Dissipation Curve



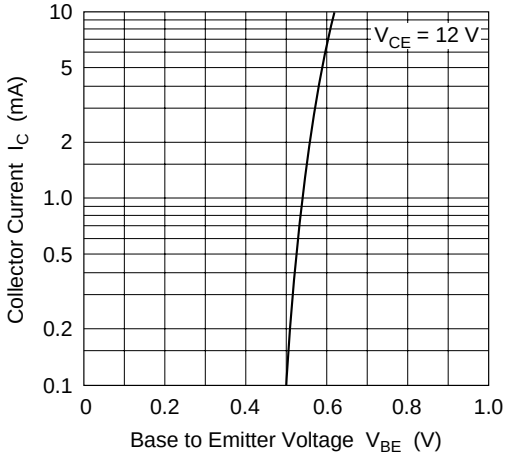
Typical Output Characteristics



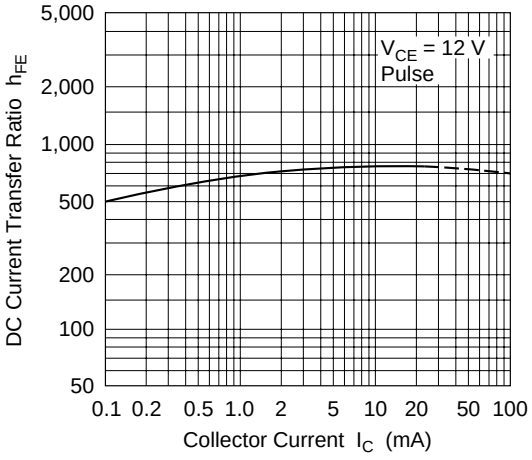
Typical Output Characteristics



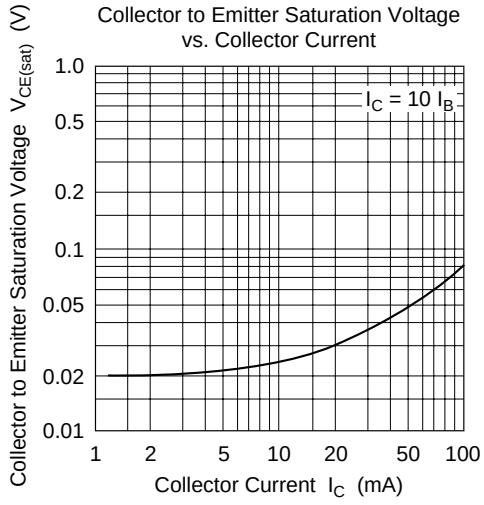
Typical Transfer Characteristics



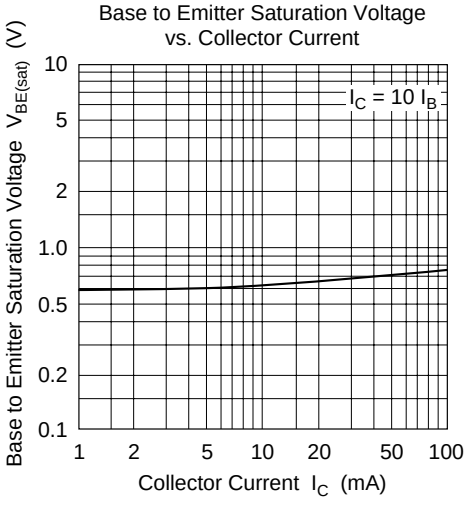
DC Current Transfer Ratio vs. Collector Current



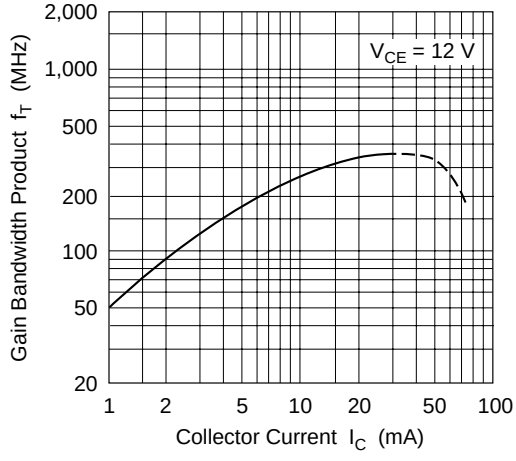
Collector to Emitter Saturation Voltage vs. Collector Current



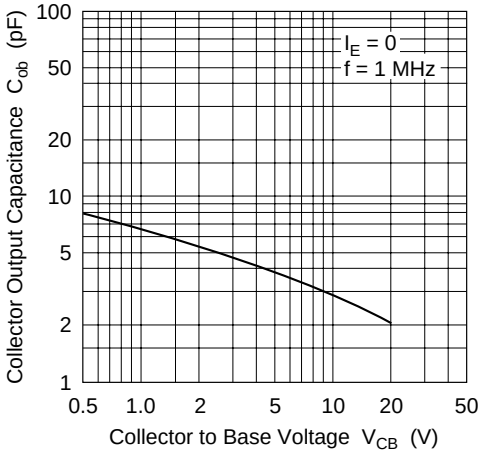
Base to Emitter Saturation Voltage vs. Collector Current



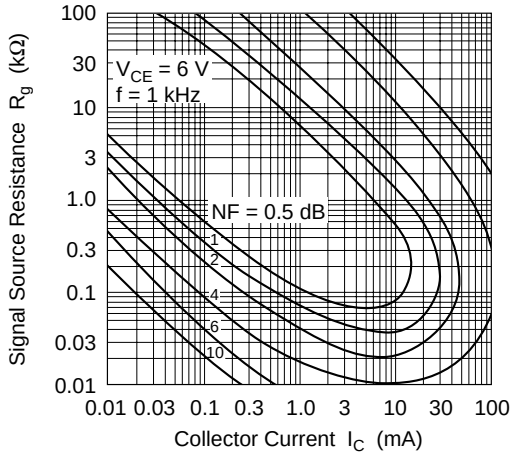
Gain Bandwidth Product vs. Collector Current



Collector Output Capacitance vs. Collector to Base Voltage



Contours of Constant Noise Figure



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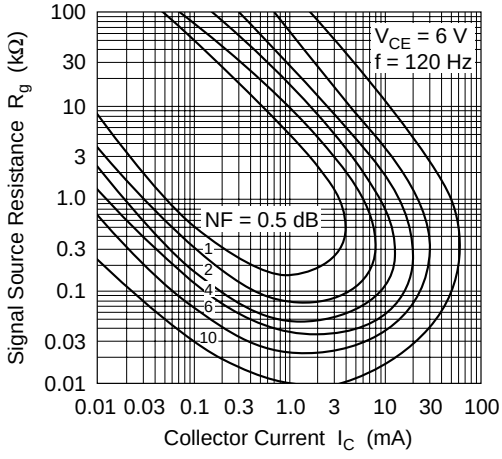

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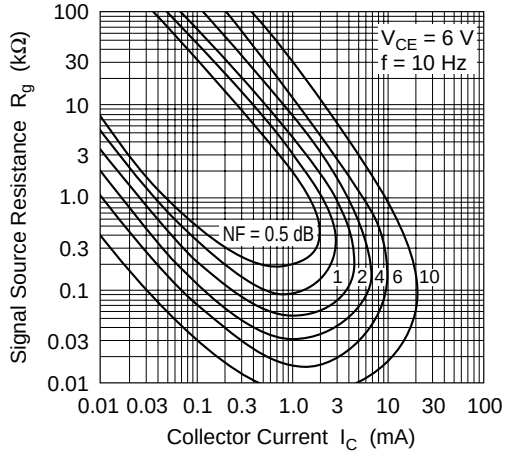
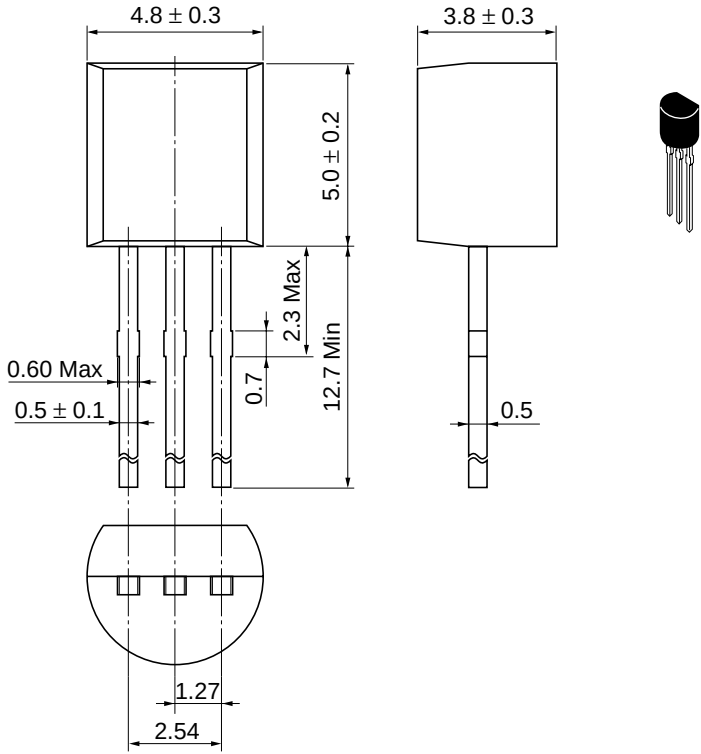


Unit: mm



Hitachi Code	TO-92 (1)
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.25 g

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